

## ST300C..L SERIES

### PHASE CONTROL THYRISTORS

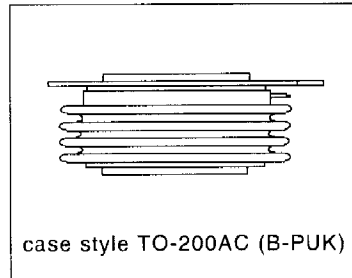
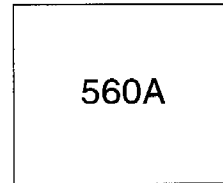
Hockey Puk Version

#### Features

- Center amplifying gate
- Metal case with ceramic insulator
- International standard case TO-200AC (B-PUK)

#### Typical Applications

- DC motor controls
- Controlled DC power supplies
- AC controllers



case style TO-200AC (B-PUK)

#### Major Ratings and Characteristics

Parameters	ST300C..L	Units
$I_{T(AV)}$	560	A
@ $T_{hs}$	55	°C
$I_{T(RMS)}$	1115	A
@ $T_{hs}$	25	°C
$I_{TSM}$	@ 50Hz	8000
	@ 60Hz	8380
$I^2t$	@ 50Hz	320
	@ 60Hz	292
$V_{DRM}/V_{RRM}$	400 to 2000	V
$t_q$	typical	100
$T_J$	- 40 to 125	°C

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## ST300C..L Series

### ELECTRICAL SPECIFICATIONS

#### Voltage Ratings

Type number	Voltage Code	$V_{DRM}/V_{RRM}$ max. repetitive peak and off-state voltage V	$V_{RSM}$ maximum non-repetitive peak voltage V	$I_{DRM}/I_{RRM}$ max. @ $T_J = T_J \text{ max}$ mA
ST300C..L	04	400	500	50
	08	800	900	
	12	1200	1300	
	16	1600	1700	
	18	1800	1900	
	20	2000	2100	

#### On-state Conduction

Parameter	ST300C..L	Units	Conditions		
$I_{T(AV)}$ Max. average on-state current @ Heatsink temperature	560 (275)	A	180° conduction, half sine wave double side (single side) cooled		
	55 (75)	°C			
$I_{T(RMS)}$ Max. RMS on-state current	1115	A	DC @ 25°C heatsink temperature double side cooled		
$I_{TSM}$ Max. peak, one-cycle non-repetitive surge current	8000		t = 10ms	No voltage	
	8380		t = 8.3ms	reapplied	
	6730		t = 10ms	100% $V_{RRM}$	
	7040		t = 8.3ms	reapplied	
$I^2t$ Maximum $I^2t$ for fusing	320	KA <sup>2</sup> s	t = 10ms	No voltage	Sinusoidal half wave, Initial $T_J = T_J \text{ max}$ .
	292		t = 8.3ms	reapplied	
	226		t = 10ms	100% $V_{RRM}$	
	207		t = 8.3ms	reapplied	
$I^2\sqrt{t}$ Maximum $I^2\sqrt{t}$ for fusing	3200	KA <sup>2</sup> \s	t = 0.1 to 10ms, no voltage reapplied		
$V_{T(TO)1}$ Low level value of threshold voltage	0.97	V	$(16.7\% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$ , $T_J = T_J \text{ max}$ .		
$V_{T(TO)2}$ High level value of threshold voltage	0.98		$(I > \pi \times I_{T(AV)})$ , $T_J = T_J \text{ max}$ .		
$r_{T1}$ Low level value of on-state slope resistance	0.74	mΩ	$(16.7\% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$ , $T_J = T_J \text{ max}$ .		
$r_{T2}$ High level value of on-state slope resistance	0.73		$(I > \pi \times I_{T(AV)})$ , $T_J = T_J \text{ max}$ .		
$V_{TM}$ Max. on-state voltage	2.18	V	$I_{pk} = 1635A$ , $T_J = T_J \text{ max}$ , $t_p = 10ms$ sine pulse		
$I_H$ Maximum holding current	600	mA	$T_J = 25°C$ , anode supply 12V resistive load		
$I_L$ Typical latching current	1000				

## ST300C..L Series

### Switching

Parameter	ST300C..L	Units	Conditions
di/dt Max. non-repetitive rate of rise of turned-on current	1000	A/μs	Gate drive 20V, 20Ω, $t_r \leq 1\mu s$ $T_J = T_J \text{ max. anode voltage} \leq 80\% V_{DRM}$
$t_d$ Typical delay time	1.0	μs	Gate current 1A, $di_g/dt = 1A/\mu s$ $V_d = 0.67\% V_{DRM}$ , $T_J = 25^\circ C$
$t_q$ Typical turn-off time	100		$I_M = 550A$ , $T_J = T_J \text{ max. } di/dt = 40A/\mu s$ , $V_R = 50V$ $dv/dt = 20V/\mu s$ , Gate 0V 100Ω, $t_p = 500\mu s$

### Blocking

Parameter	ST300C..L	Units	Conditions
dv/dt Maximum critical rate of rise of off-state voltage	500	V/μs	$T_J = T_J \text{ max. linear to } 80\% \text{ rated } V_{DRM}$
$I_{RRM}$ $I_{DRM}$ Max. peak reverse and off-state leakage current	50	mA	$T_J = T_J \text{ max. rated } V_{DRM}/V_{RRM} \text{ applied}$

### Triggering

Parameter	ST300C..L		Units	Conditions
$P_{GM}$ Maximum peak gate power	10.0		W	$T_J = T_J \text{ max. } t_p \leq 5ms$
$P_{G(AV)}$ Maximum average gate power	2.0			$T_J = T_J \text{ max. } f = 50Hz, d\% = 50$
$I_{GM}$ Max. peak positive gate current	3.0		A	$T_J = T_J \text{ max. } t_p \leq 5ms$
$+V_{GM}$ Maximum peak positive gate voltage	20		V	$T_J = T_J \text{ max. } t_p \leq 5ms$
$-V_{GM}$ Maximum peak negative gate voltage	5.0			
$I_{GT}$ DC gate current required to trigger	TYP.	MAX.	mA	$T_J = -40^\circ C$ $T_J = 25^\circ C$ $T_J = 125^\circ C$  Max. required gate trigger/ current/ voltage are the lowest value which will trigger all units 12V anode-to-cathode applied
	200	-		
	100	200		
$V_{GT}$ DC gate voltage required to trigger	2.5	-	V	$T_J = -40^\circ C$ $T_J = 25^\circ C$ $T_J = 125^\circ C$
	1.8	3.0		
	1.1	-		
$I_{GD}$ DC gate current not to trigger	10.0		mA	$T_J = T_J \text{ max}$  Max. gate current/voltage not to trigger is the max. value which will not trigger any unit with rated $V_{DRM}$ anode-to-cathode applied
$V_{GD}$ DC gate voltage not to trigger	0.25		V	

## ST300C..L Series

### Thermal and Mechanical Specification

Parameter	ST300C..L	Units	Conditions
$T_J$ Max. operating temperature range	-40 to 125	°C	
$T_{stg}$ Max. storage temperature range	-40 to 150		
$R_{thJ-hs}$ Max. thermal resistance, junction to heatsink	0.11	K/W	DC operation single side cooled
	0.05		DC operation double side cooled
$R_{thC-hs}$ Max. thermal resistance, case to heatsink	0.011	K/W	DC operation single side cooled
	0.006		DC operation double side cooled
F Mounting force, $\pm 10\%$	9800 (1000)	N (Kg)	
wt Approximate weight	250	g	
Case style	TO-200AC (B-PUK)		See Outline Table

### $\Delta R_{thJ-hs}$ Conduction

(The following table shows the increment of thermal resistance  $R_{thJ-hs}$  when devices operate at different conduction angles than DC)

Conduction angle	Sinusoidal conduction		Rectangular conduction		Units	Conditions
	Single Side	Double Side	Single Side	Double Side		
180°	0.012	0.010	0.008	0.008	K/W	$T_J = T_J \text{ max.}$
120°	0.014	0.015	0.014	0.014		
90°	0.018	0.018	0.019	0.019		
60°	0.026	0.027	0.027	0.028		
30°	0.045	0.046	0.046	0.046		

### Ordering Information Table

Device Code							
ST	30	0	C	20	L	1	
①	②	③	④	⑤	⑥	⑦	⑧
<b>1</b>	- Thyristor						
<b>2</b>	- Essential part number						
<b>3</b>	- 0 = Converter grade						
<b>4</b>	- C = Ceramic Puk						
<b>5</b>	- Voltage code: Code x 100 = $V_{RRM}$ (See Voltage Rating Table)						
<b>6</b>	- L = Puk Case TO-200AC (B-PUK)						
<b>7</b>	- 0 = Eyelet terminals (Gate and Auxiliary Cathode Unsoldered Leads)						
	1 = Fast-on terminals (Gate and Auxiliary Cathode Unsoldered Leads)						
	2 = Eyelet terminals (Gate and Auxiliary Cathode Soldered Leads)						
	3 = Fast-on terminals (Gate and Auxiliary Cathode Soldered Leads)						
<b>8</b>	- Critical dv/dt: None = 500V/ $\mu$ sec (Standard value)						
	L = 1000V/ $\mu$ sec (Special selection)						

**ST300C..L Series**

**Outline Table**

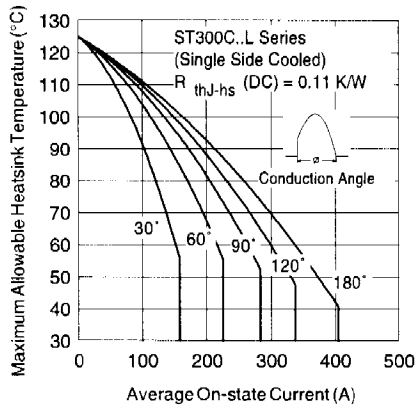
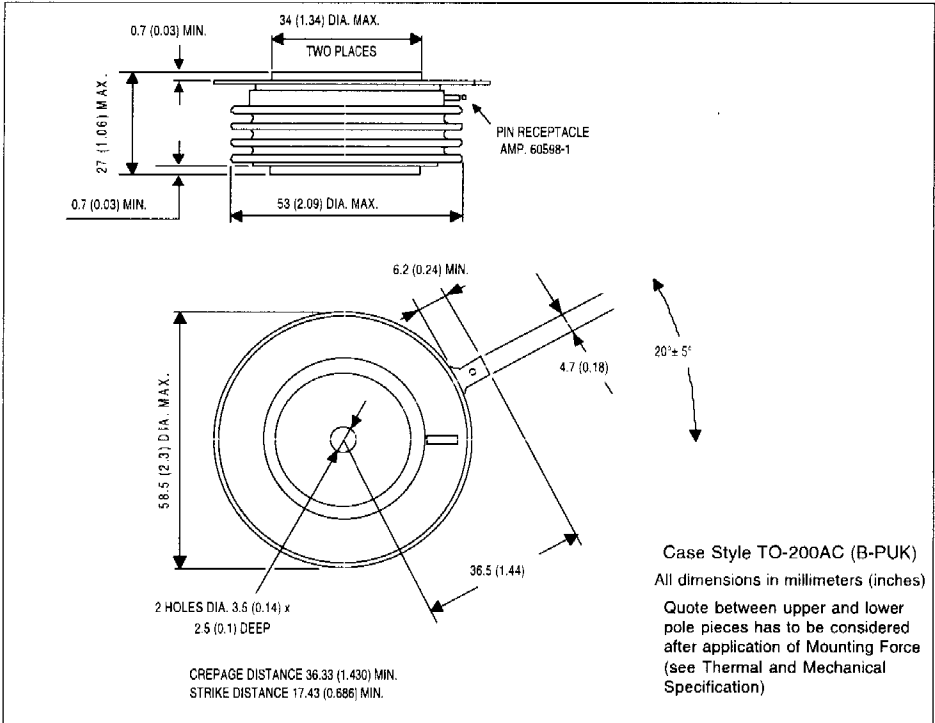


Fig. 1 - Current Ratings Characteristics

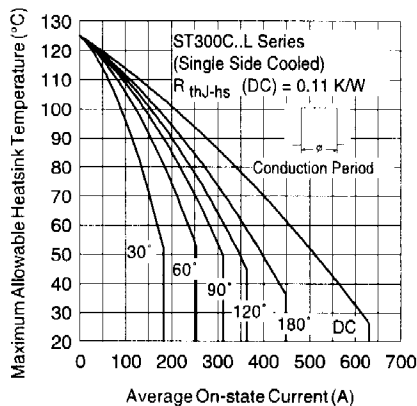


Fig. 2 - Current Ratings Characteristics